TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC74LCX374F,TC74LCX374FT,TC74LCX374FK

Low-Voltage Octal D-Type Flip-Flop with 5-V Tolerant Inputs and Outputs

The TC74LCX374 is a high-performance CMOS octal D-type flip-flop. Designed for use in 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

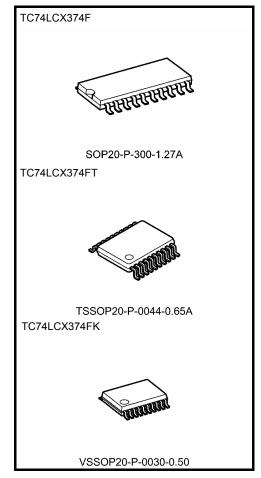
The device is designed for low-voltage (3.3 V) VCC applications, but it could be used to interface to 5-V supply environment for both inputs and outputs.

This 8 bit D-type flip-flop is controlled by a clock input (CK) and an output enable input  $(\overline{OE})$ . When the  $\overline{OE}$  input is high, the eight outputs are in a high impedance state.

All inputs are equipped with protection circuits against static discharge.

#### **Features**

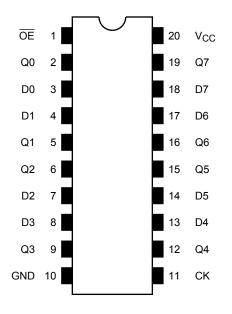
- Low-voltage operation: VCC = 2.0 to 3.6 V
- High-speed operation:  $t_{pd} = 8.5 \text{ ns (max) (V}_{CC} = 3.0 \text{ to } 3.6 \text{ V)}$
- Output current:  $|I_{OH}|/I_{OL} = 24 \text{ mA (min)} (V_{CC} = 3.0 \text{ V})$
- Latch-up performance: -500 mA
- Available in JEITA SOP, TSSOP and VSSOP (US)
- · Power-down protection provided on all inputs and outputs
- Pin and function compatible with the 74 series (74AC/VHC/HC/F/ALS/LS etc.) 374 type



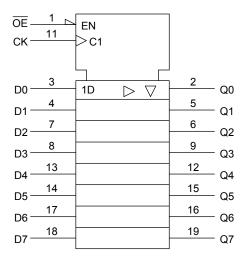
Weight

SOP20-P-300-1.27A : 0.22 g (typ.) TSSOP20-P-0044-0.65A : 0.08 g (typ.) VSSOP20-P-0030-0.50 : 0.03 g (typ.)

# Pin Assignment (top view)



### **IEC Logic Symbol**



### **Truth Table**

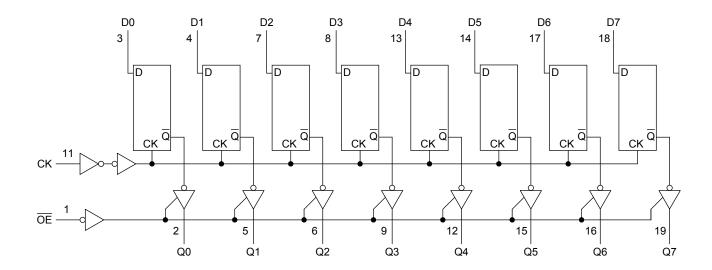
·	Inputs	_	Outputs
ŌĒ	CK	D	Outputs
Н	X	X	Z
L	$\overline{}$	Х	Qn
L		L	L
L		Н	Н

X: Don't care

Z: High impedance

Qn: No change

### **System Diagram**





#### **Absolute Maximum Ratings (Note 1)**

Characteristics	Symbol	Rating	Unit
Power supply voltage	V <sub>CC</sub>	-0.5 to 7.0	V
DC input voltage	V <sub>IN</sub>	-0.5 to 7.0	V
		-0.5 to 7.0 (Note 2)	
DC output voltage	V <sub>OUT</sub>	-0.5 to V <sub>CC</sub> + 0.5	V
		(Note 3)	
Input diode current	l <sub>IK</sub>	-50	mA
Output diode current	lok	±50 (Note 4)	mA
DC output current	lout	±50	mA
Power dissipation	PD	180	mW
DC V <sub>CC</sub> /ground current	I <sub>CC</sub> /I <sub>GND</sub>	±100	mA
Storage temperature	T <sub>stg</sub>	-65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: Output in OFF state

Note 3: High or low state. IOUT absolute maximum rating must be observed.

Note 4:  $V_{OUT} < GND$ ,  $V_{OUT} > V_{CC}$ 

#### **Operating Ranges (Note 1)**

Characteristics	Symbol	Rating	Unit		
Power supply voltage	V <sub>CC</sub>	2.0 to 3.6	V		
Tower supply voitage	VCC	1.5 to 3.6 (Note 2)	V		
Input voltage	V <sub>IN</sub>	0 to 5.5	V		
Output voltage	V	0 to 5.5 (Note 3)	V		
Output voltage	V <sub>OUT</sub>	0 to V <sub>CC</sub> (Note 4)	V		
Output current	la/la.	±24 (Note 5)	mA		
Output current	I <sub>OH</sub> /I <sub>OL</sub>	±12 (Note 6)	IIIA		
Operating temperature	T <sub>opr</sub>	–40 to 85	°C		
Input rise and fall time	dt/dv	0 to 10 (Note 7)	ns/V		

Note 1: The operating ranges must be maintained to ensure the normal operation of the device.

Unused inputs must be tied to either VCC or GND.

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Note 2: Data retention only

Note 3: Output in OFF state

Note 4: High or low state

Note 5:  $V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$ 

Note 6:  $V_{CC} = 2.7 \text{ to } 3.0 \text{ V}$ 

Note 7:  $V_{IN} = 0.8$  to 2.0 V,  $V_{CC} = 3.0$  V



### **Electrical Characteristics**

### DC Characteristics ( $Ta = -40 \text{ to } 85^{\circ}\text{C}$ )

Characteris	etics	Symbol	Test Condition		V <sub>CC</sub> (V)	Min	Max	Unit	
	H-level	V <sub>IH</sub>	_		2.7 to 3.6	2.0	_		
Input voltage	L-level	V <sub>IL</sub>	-	_	2.7 to 3.6	_	0.8	V	
				I <sub>OH</sub> = -100 μA	2.7 to 3.6	V <sub>CC</sub> - 0.2	_		
	H-level	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -12 mA	2.7	2.2	_		
				I <sub>OH</sub> = -18 mA	3.0	2.4	_		
Output voltage				I <sub>OH</sub> = -24 mA	3.0	2.2	_	V	
				I <sub>OL</sub> = 100 μA	2.7 to 3.6	_	0.2		
	L-level			I <sub>OL</sub> = 12 mA	2.7	_	0.4		
	L-level	V <sub>OL</sub>	$V_{IN} = V_{IH}$ or $V_{IL}$	I <sub>OL</sub> = 16 mA	3.0	_	0.4		
			I <sub>OL</sub> =	I <sub>OL</sub> = 24 mA	3.0	_	0.55		
Input leakage current		I <sub>IN</sub>	V <sub>IN</sub> = 0 to 5.5 V	V <sub>IN</sub> = 0 to 5.5 V		_	±5.0	μА	
3-state output OFF st	tput OFF state current I <sub>OZ</sub>		$V_{IN} = V_{IH}$ or $V_{IL}$ $V_{OUT} = 0$ to 5.5 V		2.7 to 3.6	_	±5.0	μА	
Power-off leakage cu	rrent	l <sub>OFF</sub>	V <sub>IN</sub> /V <sub>OUT</sub> = 5.5 V		0	_	10.0	μΑ	
Ouissant supply sur	rant		V <sub>IN</sub> = V <sub>CC</sub> or GND		V <sub>IN</sub> = V <sub>CC</sub> or GND		_	10.0	
Quiescent supply curr	EIIL	Icc	V <sub>IN</sub> /V <sub>OUT</sub> = 3.6 to 5.5 V		2.7 to 3.6	_	±10.0	μА	
Increase in I <sub>CC</sub> per in	put	Δl <sub>CC</sub>	$V_{IH} = V_{CC} - 0.6 V$		2.7 to 3.6		500		

### AC Characteristics ( $Ta = -40 \text{ to } 85^{\circ}\text{C}$ )

Characteristics	Symbol	Test Condition		Min	Max	Unit
Ondradicholido	Cymbol	rest contaition			IVIGA	Offic
Maximum clock frequency	f <sub>max</sub>	Figure 1, Figure 2	2.7	_		MHz
maximum clock frequency	ттах	rigure 1, rigure 2	$3.3 \pm 0.3$	150		IVII IZ
Propagation delay time	t <sub>pLH</sub>	Figure 1, Figure 2	2.7	_	9.5	ns
(CK-Q)	t <sub>pHL</sub>	rigure 1, rigure 2	$3.3 \pm 0.3$	1.5	8.5	113
Output enable time	t <sub>pZL</sub>	Figure 1, Figure 3	2.7	_	9.5	ns
Output enable time	t <sub>pZH</sub>	rigure 1, rigure 3	$3.3 \pm 0.3$	1.5	8.5	113
Output disable time	t <sub>pLZ</sub> Figure 1 Figure 2	Figure 1, Figure 3	2.7	_	8.5	ns
Output disable time	t <sub>pHZ</sub>	rigure 1, rigure 3	$3.3 \pm 0.3$	1.5	7.5	113
Minimum pulse width	t <sub>w</sub> (H)	Figure 1, Figure 2	2.7	4.0		ns
(CK)	t <sub>w</sub> (L)	rigure 1, rigure 2	$3.3 \pm 0.3$	3.3		113
Minimum setup time	t <sub>s</sub>	Figure 1, Figure 2	2.7	2.5		ns
williman setap time	is is	rigure 1, rigure 2	$3.3 \pm 0.3$	2.5		113
Minimum hold time	t <sub>h</sub>	Figure 1, Figure 2	2.7	1.5		ns
		rigure 1, rigure 2	$3.3 \pm 0.3$	1.5		113
Output to output skew	t <sub>osLH</sub>	(Note)	2.7	_	_	ns
Output to output sitew	to shi	$3.3 \pm 0.3$	_	1.0	113	

Note: Parameter guaranteed by design.

 $(t_{\text{OSLH}} = |t_{\text{pLHm}} - t_{\text{pLHn}}|, \, t_{\text{OSHL}} = |t_{\text{pHLm}} - t_{\text{pHLn}}|)$ 



### Dynamic Switching Characteristics (Ta = 25°C, input: $t_r = t_f = 2.5$ ns, $C_L = 50$ pF, $R_L = 500 \Omega$ )

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Тур.	Unit
Quiet output maximum dynamic V <sub>OL</sub>	V <sub>OLP</sub>	V <sub>IH</sub> = 3.3 V, V <sub>IL</sub> = 0 V	3.3	0.8	٧
Quiet output minimum dynamic V <sub>OL</sub>	V <sub>OLV</sub>	V <sub>IH</sub> = 3.3 V, V <sub>IL</sub> = 0 V	3.3	0.8	٧

#### **Capacitive Characteristics (Ta = 25°C)**

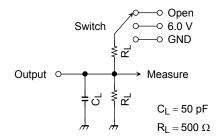
Characteristics	Symbol	Test Condition	V	CC (V)	Тур.	Unit
Input capacitance	C <sub>IN</sub>	_		3.3	7	pF
Output capacitance	C <sub>OUT</sub>	_		3.3	8	pF
Power dissipation capacitance	C <sub>PD</sub>	$f_{IN} = 10 \text{ MHz}$ (N	ote)	3.3	25	pF

Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 \text{ (per bit)}$ 

#### **AC Test Circuit**



Parameter	Switch
t <sub>pLH</sub> , t <sub>pHL</sub>	Open
t <sub>pLZ</sub> , t <sub>pZL</sub>	6.0 V
t <sub>pHZ</sub> , t <sub>pZH</sub>	GND
$t_{\rm W}$ , $t_{\rm S}$ , $t_{\rm h}$ , $t_{\rm max}$	Open

Figure 1

#### **AC Waveform**

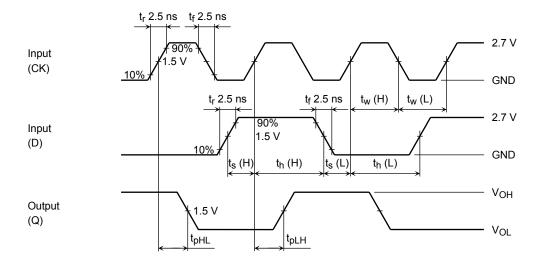


Figure 2 tpLH, tpHL, tw, ts, th

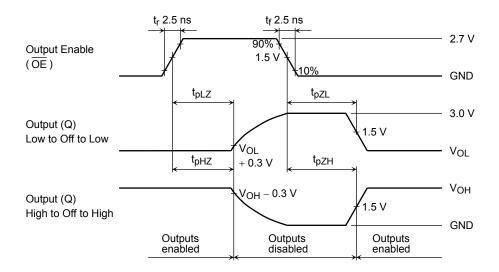
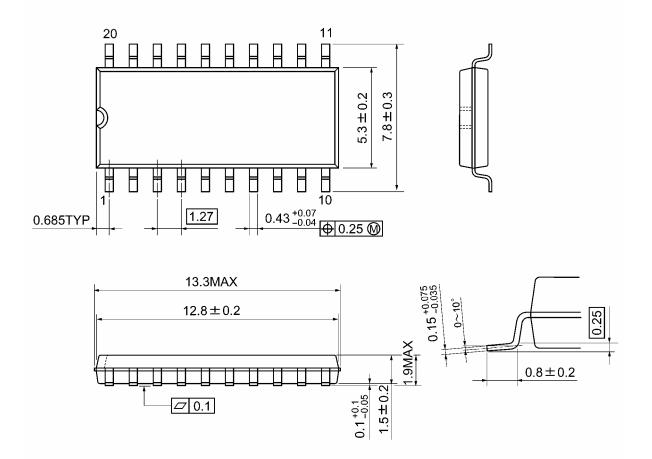


Figure 3  $t_{\text{pLZ}},\,t_{\text{pHZ}},\,t_{\text{pZL}},\,t_{\text{pZH}}$ 

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## **Package Dimensions**

SOP20-P-300-1.27A Unit: mm



Weight: 0.22 g (typ.)

(0.5)

0.45~0.75

## **Package Dimensions**

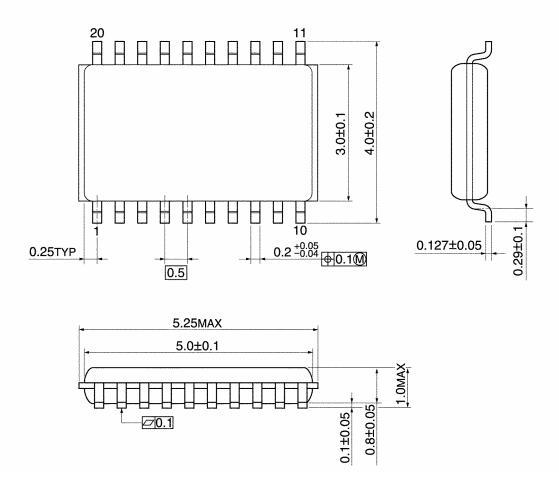
TSSOP20-P-0044-0.65A Unit: mm  $6.4\pm0.2$  $0.22\substack{+0.09 \\ -0.06}$ 0.65 0.325TYP <del>| |</del>0.13M 6.9MAX 6.5±0.1 1.2MAX 0~10 1.0±0.05 0.1±0.05 S

Weight: 0.08 g (typ.)

**∅**0.1|S

## **Package Dimensions**

VSSOP20-P-0030-0.50 Unit: mm



Weight: 0.03 g (typ.)

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20070701-EN GENERAL

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